

Technical Explanation SKYPER® 12 PV

Revision:	03
Issue date:	2020-05-25
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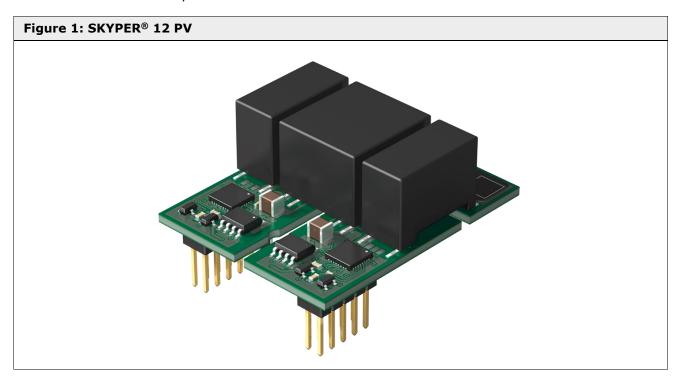
Keyword: IGBT driver core, L5070901

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1. Introduction

The SKYPER® 12 PV is the most compact driver core within the SKYPER® family and demonstrates its real advantages in low and medium power photovoltaic and ESS applications. In spite of its unrivalled compactness of only 36mm x 45mm the SKYPER® 12 PV provides reinforced insulation for operating voltages of up to 1500 VDC in accordance with EN62109-1 & EN61800-5-1. The powerful output stages of 20A peak current per channel drives semiconductor module with gate charges of up to 20 μ C reliably. SEMIKRON's highly integrated ASIC technology allows using 30% fewer components than standard solutions which achieve a MTBF rate of 12 million hours at full load for the dual-channel driver core in accordance with the industry standard SN29500.



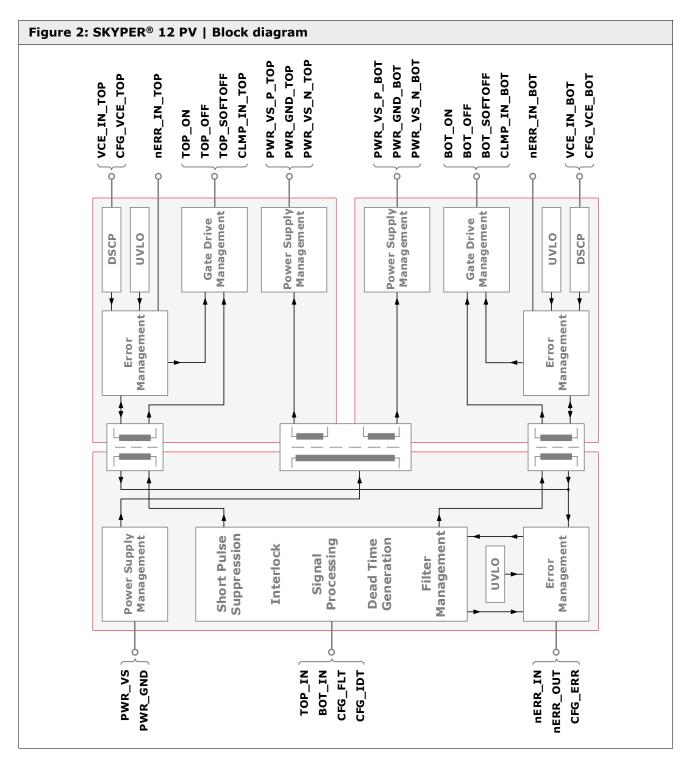
KEY FEATURES

- Two output channels
- 1.25W output power and 20A peak output current per channel
- Up to 1500V DC-Link voltage
- ±3 ns jitter per channel
- Fully isolated secondary side power supply
- Selectable filter settings
- Soft turn-off in case of any secondary side error event
- Short pulse suppression (SPS)
- Under voltage lockout (UVLO)
- Dynamic short circuit protection (DSCP)
- Selectable error management modes for standard and multilevel applications
- MTBF rate > 12 Million hours at full load



2. Block Diagram and Application Example

2.1 Block diagram





2.2 Application example

Figure 3 and Figure 4 show a typical SKYPER® 12 PV core setup to control a multilevel semiconductor module. The SKYPER® 12 PV employs SEMIKRON's highly-integrated ASIC chipset allowing easy configuration with only a few simple external circuits and in turn reducing the project and development time as well as the cost.

2.2.1 Primary side

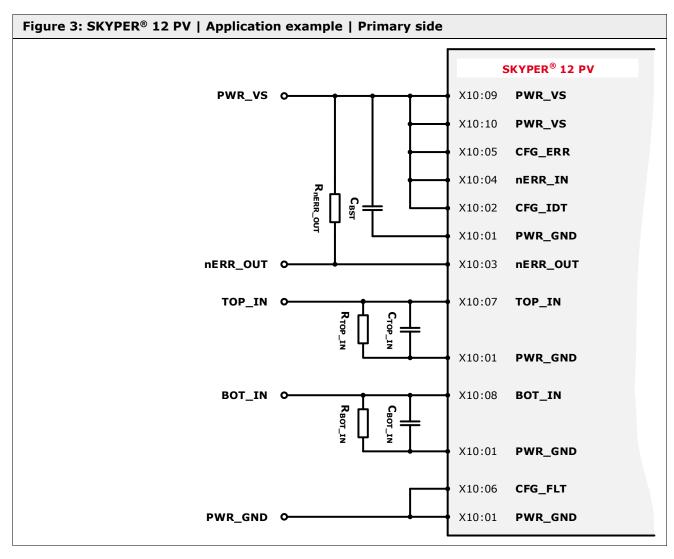


Table 1: SKYPER® 12 PV Application example Primary side Recommended values			
Component	Value	Remark	
C _{TOP_IN} / C _{BOT_IN}	1nF	Optional filter capacitors suppressing high-frequency signals. For further information please refer to [3].	
C _{BST}	-	Optional boost capacitor, dimensioning according to chapter 4.11.	
R _{TOP_IN} / R _{BOT_IN}	10kΩ	Optional pull-down resistors, for steady off state of the corresponding output, if no input signal is applied.	
R _{nERR_OUT}	4.75kΩ	Optional pull-up resistor, mandatory if error output is used. Dimensioning according to chapter 4.6	



2.2.2 Secondary side

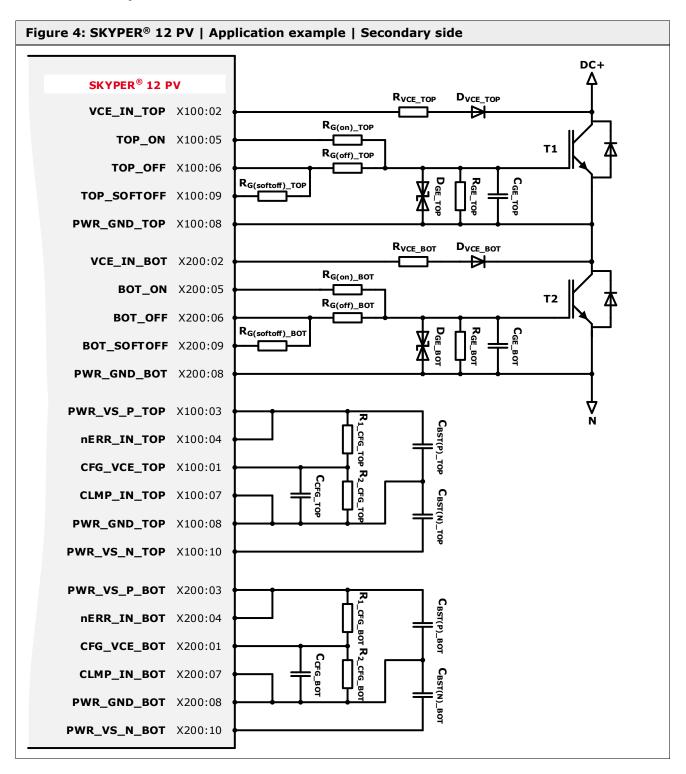




Table 2: SKYPER® 12 PV Application example Secondary side Recommended values			
Component	Value	Remark	
C _{BST(P)_TOP} / C _{BST(N)_TOP} C _{BST(P)_BOT} / C _{BST(N)_BOT}	-	Optional boost capacitors, dimensioning according to chapter 4.11.	
C _{CFG_TOP} / C _{CFG_BOT}	-	Optional capacitor to adjust the blanking time $t_{\text{bl(VCE)}}$ of the dynamic short circuit protection function. Necessary , if DSCP is used. Dimensioning according to chapter 5.5.	
C _{GE_TOP} / C _{GE_BOT}	-	Optional capacitor to prevent gate oscillation in case of short circuit events or in case of parallel operation of semiconductor power modules. For further information please refer to [3].	
D _{GE_TOP} / D _{GE_BOT}	$V_{Rmin} \ge V_{G(on)} + 10\%$	Optional suppressor diode to prevent gate voltage overshoots. For further information please refer to [3].	
D _{VCE_TOP} / D _{VCE_BOT}	-	Optional high voltage diode for V_{CE} -monitoring, mandatory if DSCP is used. Dimensioning according to chapter 5.5.	
R _{1_CFG_TOP} / R _{1_CFG_BOT}	≥ 10kΩ	Optional resistors to adjust the trip level V _{CE(ref)} of the dynamic short circuit protection, necessary if DCSP is used. Dimensioning according to chapter 5.5.	
R _{2_CFG_TOP} / R _{2_CFG_BOT}	-	Optional resistors to adjust the trip level V _{CE(ref)} of the dynamic short circuit protection, necessary if DCSP is used. Dimensioning according to chapter 5.5.	
R _{GE_TOP} / R _{GE_BOT}	10kΩ	Optional resistor to avoid an open gate of the semiconductor, if the driver is not supplied. For further information refer to [3].	
$\begin{array}{c} R_{G(off)_TOP} / R_{G(off)_BOT} \\ R_{G(on)_TOP} / R_{G(on)_BOT} \end{array}$	≥ 1.25Ω	Necessary resistors to adjust the semiconductors' turn-on and turn-off behavior. Dimensioning according to chapter 4.10.	
R _G (softoff)_TOP R _G (softoff)_BOT	≥ 1Ω	Mandatory resistor to adjust the semiconductors' turn-off behavior in case of soft turn-off. Dimensioning according to chapter 4.10.	
R _{VCE_TOP} / R _{VCE_BOT}	511Ω	Optional series resistor for V_{CE} -monitoring, mandatory if DSCP is used.	



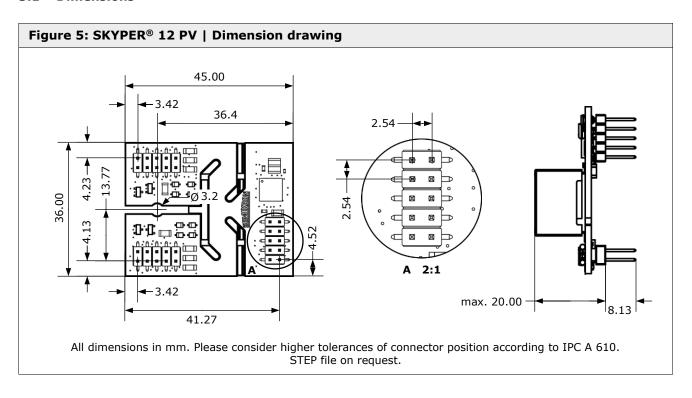
Referring to the application example shown in Figure 3 and Figure 4, Table 3 describes the settings made.

Table 3: SKYPER® 12	Table 3: SKYPER® 12 PV Application example Settings				
Function	Configuration	Remark	Chapter		
Active clamping	Disabled	Disabled by connecting the pins CLMP_IN_TOP and CLMP_IN_BOT to the corresponding PWR_GND pins.	5.6		
Bidirectional error (=HALT)	Disabled	Disabled by connecting the pin nERR_IN to pin PWR_VS.	4.7		
Dynamic short circuit protection (DSCP)	Enabled at both output channels	Enabled by connecting the pins VCE_IN_TOP and VCE_IN_BOT to the corresponding collectors of the semiconductors through R_{VCE_TOP} , D_{VCE_TOP} and R_{VCE_BOT} , D_{VCE_BOT} . DSCP configuration via pins CFG_VCE_TOP and CFG_VCE_BOT .	5.5		
Dead time generation	Disabled	Disabled by connecting pin <i>CFG_IDT</i> to pin <i>PWR_VS</i> .	5.2		
Error mode	In case of any secondary side error condition the event will be reported at the pin nERR_OUT. The driver turns-off the affected output immediately and the second output with the next turn-off signal at the corresponding input. Both outputs remain blocked until the error state is reset .	Selected by connecting pin <i>CFG_ERR</i> to pin <i>PWR_VS</i> .	5.1		
Error propagation delay time	700ns (typical value)	Fixed value.	5.1		
External error	Disabled at both secondary sides.	Disabled by connecting the pins nERR_IN_TOP and nERR_IN_BOT to the corresponding PWR_VS pins.	5.1		
Filter	Analogue	Selected by connecting pin <i>CFG_FLT</i> to pin <i>PWR_GND</i> .	5.3		
Interlock	Disabled	Disabled by connecting pin <i>CFG_IDT</i> to pin <i>PWR_VS</i> .	5.2		
Jitter	±3ns (typical value)	Selected by connecting the pin CFG_FLT to pin PWR_GND.	4.5		
Short pulse suppression (SPS)	200 ns (typical value)	Selected by connecting pin <i>CFG_FLT</i> to pin <i>PWR_GND</i> .	5.3		
Undervoltage lockout (UVLO)	Always active on primary and secondary side	-	5.4		



3. Dimensions and mechanical precautions

3.1 Dimensions



3.2 Plug-in connection

The SKYPER® 12 PV provides simple electrical and mechanical connection to adapter or control boards by its standard pin headers. The primary side and the two secondary side plug-in connectors are 10 pin dual row 2.54mm pin headers. For a secure mechanical connection of the SKYPER 12 PV IGBT driver it is essential that the pin headers can be fully supported by the female mating connectors.

Example for a suitable female mating connector:

Description	Shape	Manufacturer	Art. no.
(female) RM2.54 10p	SMD 2ROW	Suyin	254100FA

Using SMD type mating connectors allows optimized board layout especially for SEMIKRON's spring contact modules like SEMiX.



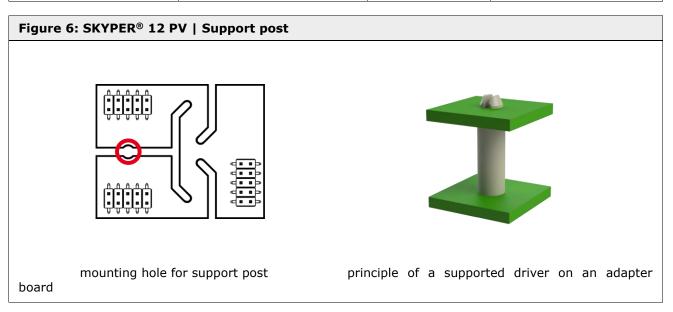
3.3 Support post

To increase the robustness of the mechanical connection between the SKYPER® 12 PV driver and the corresponding board a support post could be assembled. If a support post is used, make sure it has the correct length. A too short support post would bend both, the driver and the corresponding board that it is mounted on, thus increasing mechanical stress. If the support post is too long, the mating connectors may not fully support the pin header and insufficient or instable electrical and mechanical contact might occur.

The mounting hole is located in the insulation area between the secondary sides of the driver. To avoid reduction of creepage and clearance distances when utilizing a support post, the support post's material must have a CTI 600 classification at least.

Example of a support post:

Description	Shape	Manufacturer	Art. no.
Nylon support post	Dual lock	Essentra	DLMSPM-8-01 (>12mm)



3.4 Solder connection

The SKYPER® 12 PV driver core can be soldered directly onto an adapter or control board. It should be noted that if the driver is placed too close to the adapter or control board, the clearance distances from the driver's primary to secondary side as well as the clearance distances between the secondary sides may be reduced.

Soldering hints

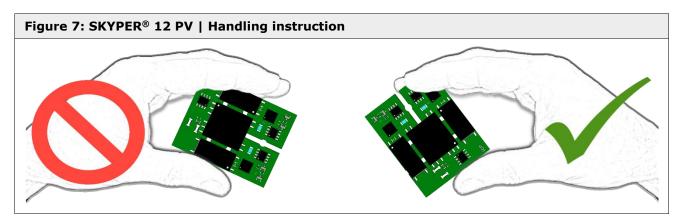
- The solder's temperature must not exceed 260°C and the solder time must not exceed 10 seconds.
- The ambient temperature must not exceed the specified maximum storage temperature of the driver.
- The solder joints should be in accordance to IPC A 610 Revision D (or later) Class 3 (Acceptability of Electronic Assemblies) to ensure an optimum connection between driver core and printed circuit board.
- The driver is not suited for hot air, reflow or infrared reflow processes.



3.5 Handling instructions

Please ensure electric static discharge protection during handling. The driver should only be removed from its original packaging just before mounting. When mounting the driver it has to be ensured that the work is done in an ESD-protected workplace environment. Persons working with the driver have to wear ESD wristbands, overalls and shoes. If tools are used for mounting, those must comply with ESD standards.

When handling the driver, do not pick up the driver at the transformers. The driver MUST be handled at the PCB sides.

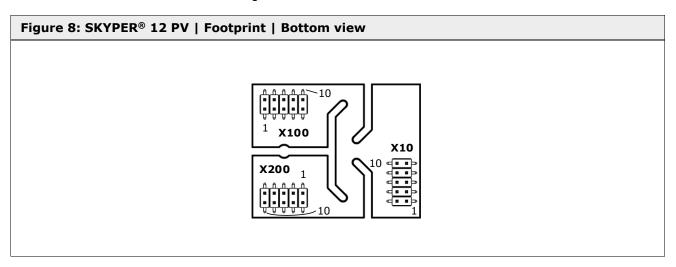




4. Interface Description

4.1 Footprint

The footprint of the SKYPER $^{\$}$ 12 PV with its primary side pin header X10 and the secondary side pin headers X100 and X200 are shown in Figure 8.



4.2 Pin assignment

4.2.1 Pin assignment of pin header X10 | Primary side

Table 4:	Table 4: SKYPER® 12 PV Pin assignment - Primary side X10			
Pin	Signal	Function	Specification	
X10:01	PWR_GND	Ground potential of power supply and digital signals	To be connected to ground	
X10:02	CFG_IDT	Interlock dead time configuration	15V logic; 150kΩ (pull-up) LOW = 2μs interlock dead time HIGH = No interlock dead time	
X10:03	nERR_OUT	Error output	Open collector output; max. 18V/15mA (external pull-up resistor needed) LOW = Error HIGH = No error	
X10:04	nERR_IN	Error input	15V logic inverted; 150kΩ/10nF (pull-up) LOW = External error HIGH = No external error	
X10:05	CFG_ERR	Error behaviour configuration in case of any error condition	15V logic; 150kΩ (pull-down) LOW = Both outputs switch off HIGH = Affected output switches off	
X10:06	CFG_FLT	Filter configuration for switching signals	15V logic; 150kΩ (pull-down) LOW = Analogue filter ($t_{SPS(ana)}$) HIGH = Digital filter ($t_{SPS(dig)}$)	
X10:07	TOP_IN	Switching signal input (TOP)	15V logic; $33k\Omega/0.01nF$ (pull-down) LOW = TOP switch off HIGH = TOP switch on	
X10:08	BOT_IN	Switching signal input (BOT)	15V logic; 33kΩ/0.01nF (pull-down) LOW = BOT switch off HIGH = BOT switch on	



X10:09	PWR_VS	Driver power supply	Stabilised +15V ±3%
X10:10	PWR_VS	Driver power supply	Stabilised +15V ±3%

4.2.2 Pin assignment of pin header X100 | Secondary side | TOP

Table 5:	Table 5: SKYPER® 12 PV Pin assignment – Secondary side TOP X100				
Pin	Signal	Function	Specification		
X100:01	CFG_VCE_TOP	V _{CE} -monitoring reference voltage	External voltage divider needed		
X100:02	VCE_IN_TOP	V _{CE} -monitoring input	External blocking diode needed		
X100:03	PWR_VS_P_TOP	Power supply output, positive voltage	Equal to $V_{G(on)}$ (external buffer capacitors can be optionally connected)		
X100:04	nERR_IN_TOP	External error input	15V logic inverted; $150k\Omega/0.01nF$ (pull-up) LOW = External error HIGH = No external error		
X100:05	TOP_ON	On signal terminal for TOP semiconductor	External gate resistor needed (under consideration of $I_{\text{out(avg)}}$, $I_{\text{out(peak)}}$, $V_{\text{G(on)}}$)		
X100:06	TOP_OFF	Off signal terminal for TOP semiconductor	External gate resistor needed (under consideration of ${}^-I_{out(avg)}$, ${}^-I_{out(peak)}$, $V_{G(off)}$)		
X100:07	CLMP_IN_TOP	V _{CE} -clamping input	$150k\Omega/0.01nF$ (pull-down) In case of activated TOP_OFF: LOW = TOP_OFF equal to $V_{G(off)}$ HIGH = TOP_OFF floating		
X100:08	PWR_GND_TOP	Ground potential of power supply and digital signals	Reference potential of gate voltages (emitter/source of power semiconductor)		
X100:09	TOP_SOFTOFF	SoftOff signal terminal for TOP semiconductor	External gate resistor needed		
X100:10	PWR_VS_N_TOP	Power supply output, negative voltage	Equal to $V_{G(off)}$ (external buffer capacitors can be optionally connected)		

4.2.3 Pin assignment of pin header X200 | Secondary side | BOT

Table 6:	Table 6: SKYPER® 12 PV Pin assignment - Secondary side BOT X200			
Pin	Signal	Function	Specification	
X200:01	CFG_VCE_BOT	V _{CE} -monitoring reference voltage	External voltage divider needed	
X200:02	VCE_IN_BOT	V _{CE} -monitoring input	External blocking diode needed	
X200:03	PWR_VS_P_BOT	Power supply output, positive voltage	Equal to $V_{G(on)}$ (external buffer capacitors can be optionally connected)	
X200:04	nERR_IN_BOT	External error input	15V logic inverted; 150k Ω /0.01nF (pull-up) LOW = External error HIGH = No external error	
X200:05	BOT_ON	On signal terminal for BOT semiconductor	External gate resistor needed (limits under consideration of $I_{\text{out(avg)}}$,	

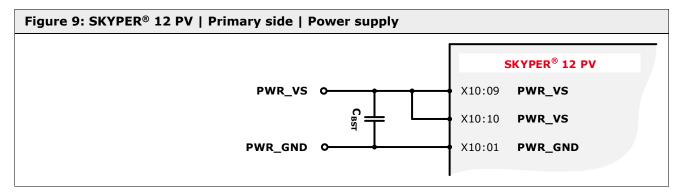


			I _{out(peak)} , V _{G(on)})
X200:06	BOT_OFF	Off signal terminal for BOT semiconductor	External gate resistor needed (limits under consideration of $-I_{out(avg)}$, $-I_{out(peak)}$, $V_{G(off)}$)
X200:07	CLMP_IN_BOT	V _{CE} -clamping input	$ 150kΩ/0.01nF (pull-down) \\ In case of activated BOT_OFF: \\ LOW = BOT_OFF equal to V_{G(off)} \\ HIGH = BOT_OFF floating $
X200:08	PWR_GND_BOT	Ground potential of power supply and digital signals	Reference potential of gate voltages (emitter/source of power semiconductor)
X200:09	BOT_SOFTOFF	SoftOff signal terminal for BOT semiconductor	External gate resistor needed
X200:10	PWR_VS_N_BOT	Power supply output, negative voltage	Equal to V _{G(off)} (external buffer capacitors can be optionally connected)

4.3 Power supply | Primary side

For a proper operation of the SKYPER® 12 PV driver core, a power supply of at least 15W/1A shall be connected to the driver's power supply pins. During power-up of the driver turn-on signals should not be applied to the driver's inputs *TOP_IN/BOT_IN*, otherwise the driver will not leave the error state.

Please note, when controlling power semiconductor modules with a gate charge \geq 2.5 μ C external boost capacitors (C_{BST}) are recommended to support the supply voltage on the primary side. Dimensioning of such boost capacitors shall be done according to chapter 4.11.

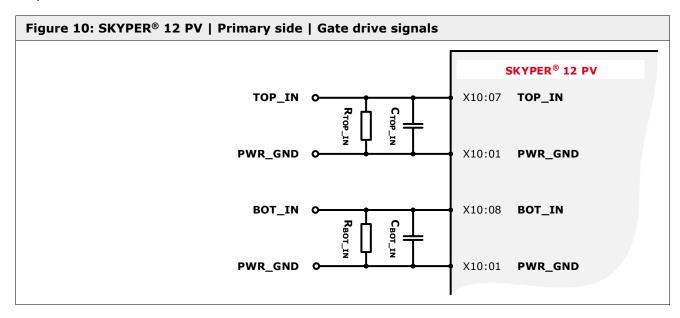




4.4 Gate drive signals | Primary side

The signal inputs TOP_IN/BOT_IN of the SKYPER® 12 PV driver core have a +15V schmitt trigger logic. A HIGH signal at the input of the driver turns on the corresponding output of the driver. A LOW signal at the input leads to a switch-off command at the corresponding output. Pulses below 1 μ s are not allowed.

Short pulses as well as voltage peaks, e.g. caused by interference, are suppressed by the driver and will not be transmitted to the outputs. Further information to the short pulse suppression are referred in chapter 5.3.



When using the driver in environments with high levels of electromagnetic noise, it is recommended to connect a filter capacitor (C_{TOP_IN}/C_{BOT_IN}) of several hundred pico Farads as close as possible to the signal inputs. Please note that these capacitors affect the propagation delay time of the driver. The R_{TOP_IN}/R_{BOT_IN} resistors pull the inputs to low-level when no control signals are applied. The recommended value of the pull-down resistors is approximately $10k\Omega$.

Parameter	Min	Тур	Max
Threshold high	-	-	10V
Threshold low	5V	-	-



4.5 Filter selection, jitter and propagation delay time | Primary side

SEMIKRON's highly-integrated mixed signal ASICs the SKYPER® 12 PV permit the selection of filter type, jitter and propagation delay time to meet specific requirements of applications.

The filter time can be set via the configuration pin *CFG_FLT*. Connecting the *CFG_FLT* pin to the *PWR_VS* pin enables the digital filter employing very low tolerances over the full temperature range.

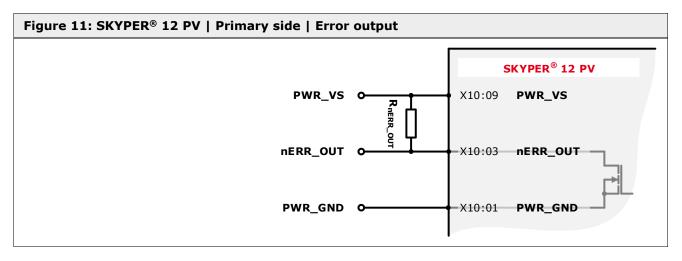
Depending on the settings made the SKYPER® 12 PV driver provides a very low jitter of typically ± 3 ns. For this mode, the analogue filter has to be enabled and the driver's internal dead time generator has to be set inactive. The dead time generator is inactive, if either the interlock feature is disabled via the *CFG_IDT* pin or the dead time of the applied pulse pattern is longer than the dead time of internal generator of the driver of typically $2\mu s$. A detailed description of the interlock function and the dead time generation is referred in chapter 5.2.

CFG_FLT	CFG_IDT	Setting	Filter time	Delay time	Jitter
HIGH	HIGH/LOW	Digital filter	390ns	830ns	±12.5ns
LOW	LOW	Analogue filter	200ns	500ns	±3ns /±12.5ns
LOW	HIGH	Analogue filter	200ns	500ns	±3ns

4.6 Error output | Primary side

The SKYPER® 12 PV reports any detected error event at the $nERR_OUT$ pin by pulling it to low-level. The error output is an open collector output and requires an external pull-up resistor (R_{nERR_OUT}). The recommended value of the pull-up resistor is in the range of $PWR_VS/I_{max,nERR_OUT} \le R_{nERR_OUT} \le 10k\Omega$. As long as the driver has not been reset the error output will be at low-level.

A detailed description, how to reset the driver to exit the error state and resume to operation is described in chapter 5.1.



Please note, if the *nERR_OUT* terminal of SKYPER® 12 PV is directly connected to a *nERR_OUT* terminal of another SKYPER® 12 PV driver, only one pull-up resistor must to be applied.



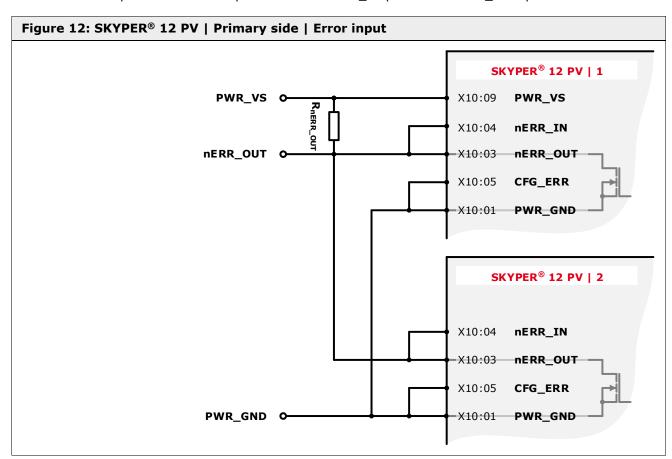
4.7 Error input | Primary side

The *nERR_IN* input is optionally used to report a system related external error event to the SKYPER® 12 PV. If the *nERR_IN* input is pulled down to low-level the driver enters into error state. Depending on the error mode configuration, described in chapter 4.8, the driver sets its outputs either immediately or with the next turn-off command at its corresponding input to low-level and locks them. After reset, as described in chapter 5.1, the driver will be ready to transfer the signals to the output stage again. If no reporting to the external error input is required, the *nERR_IN* input can be connected to the *PWR_VS* pin or to the *nERR_OUT* pin.

In multiphase or parallel operation the *nERR_IN* input offers the possibility to force the outputs of each driver in the system to off-state and locks them, simultaneously, without the need of an external control unit. Therefore all *nERR_OUT* outputs and all *nERR_IN* inputs have to be connected together forming a common bi-directional HALT line. Additionally, all *CFG_ERR* configuration pins have to be connected to ground potential, as shown in Figure 12. In this configuration, any driver connected to the HALT line can force the outputs of all connected drivers to off-state and locks them, when the driver pulls its *nERR_OUT* output to low-level.

If a specific turn-off sequence is required – as it is common practice in NPC multilevel applications – the configuration pins *CFG_ERR* have to be connected to the *PWR_VS* pins. A low-level of the HALT line locks the outputs of the connected drivers, but does not immediately force them to low-level. Outputs which are in on-state can be forced to off-state by the controller sending a turn-off command to the corresponding signal inputs *TOP_IN/BOT_IN*.

If the driver is used in environments with high levels of EMI noise, it is recommended to connect an additional filter capacitor as close as possible to the *nERR IN* pin and the *PWR GND* pin.



Parameter	Min	Тур	Max
Threshold high	-	-	11 V
Threshold low	7.5 V	-	-



4.8 Error mode selection | Primary side

The configuration pin CFG ERR selects the behavior of the SKYPER® 12 PV driver core on error events.

Connecting the *CFG_ERR* pin to the *PWR_GND* pin forces the driver to set its outputs to off-state immediately when an error is detected. As long as the driver has not been reset the error event is reported at the corresponding output and the driver's outputs are locked. Whereby, depending on whether an error is detected on the primary or on the secondary side the driver switches off the connected semiconductors via the standard turn-off or the soft-off path. If an error occurs on the primary side the driver will activate the standard turn-off paths of both channels. If an error occurs on the secondary side, the driver will activate the soft-off path of the affected secondary side. The semiconductor connected to the other secondary side will be switched off via the standard turn-off path.

If the *CFG_ERR* pin is connected to the *PWR_VS* pin, the driver locks its outputs in case of any error event's occurrence and, hence, reports the error event at the terminal *nERR_OUT*. The affected output at which the error occurred will be set to off-state, immediately. The second output will be set to off state when the driver has received a turn-off command at the corresponding signal input *TOP_OFF/BOT_OFF*. Depending on whether an error is detected on the primary or secondary side the driver activates the standard turn-off or the soft-off path, as described above.

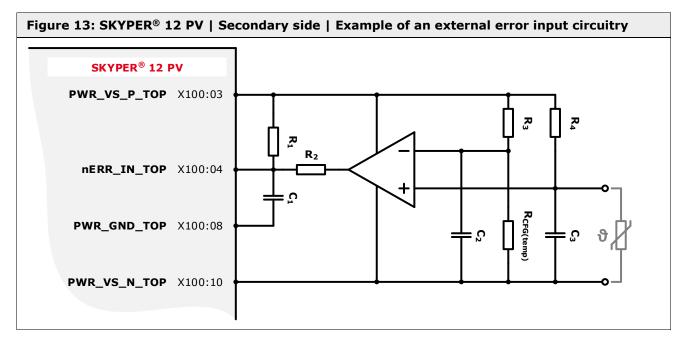
Further information related to the primary and secondary side error events, as well as on the error reset conditions is referred in chapter 5.1.

4.9 External error input | Secondary side

Each secondary side of the driver provides an error input (nERR_IN_TOP/nERR_IN_BOT) to handle external error events. These inputs are low active. Pulling one input to low-level forces the driver into error state. The behaviour of the driver in case of an external error event depends on the configuration at the configuration pin CFG_ERR, as described in chapter 4.8.

The external error input is typically used to monitor temperature, current or voltage of modules, phase legs or systems. The error input of the secondary TOP/BOT side can be disabled by connecting it to the $PWR_VS_P_TOP/PWR_VS_P_BOT$ pin.

Figure 13 shows a recommended comparator circuitry to process the NTC's signal and derive the required logic signal for the input of the SKYPER® 12 PV. When the voltage at the comparator's positive input falls below the voltage level of the negative input the $nERR_IN$ input will be pulled to low-level and generates an external error event. Assuming that resistors R_3 and R_4 have the same value the comparator's trip level is reached when the value of the NTC falls below the value of $R_{CGF(temp)}$. Please note that the negative supply pin of the comparator is connected to PWR_VS_N which has to be taken into account, in case the NTC thermistor is monitored by an external application circuit in addition.





Recommended values	Recommended values				
Component	Value	Remark			
C ₁	1nF				
C ₂	100nF				
C ₃	1µF				
R ₁	30.1kΩ				
R ₂	15kΩ				
R ₃	30.1kΩ				
R ₄	30.1kΩ				
R _{CFG(temp)}	-	The value of the resistor $R_{\text{CFG(temp)}}$ has to be determined considering the resistance characteristic of the connected thermistor and the desired trip level.			

Parameter	Min	Тур	Max
Threshold high	-	-	13 V
Threshold low	2 V	-	-



4.10 Gate resistors | Secondary side

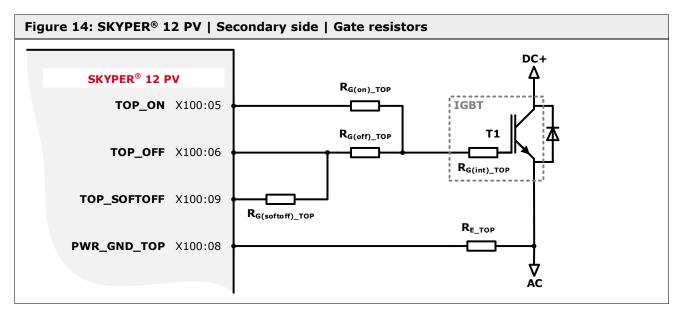
Equipped with three output channels at each secondary side (TOP_ON/TOP_OFF/TOP_SOFTOFF and BOT_ON/BOT_OFF/BOT_SOFTOFF) the SKYPER® 12 PV driver offers the possibility to optimize turn-on and turn-off behavior of the IGBT separately. By default, the driver uses the TOP_ON/TOP_OFF and BOT_ON/BOT_OFF output to turn-on or turn-off the connected semiconductor. The SOFTOFF output will be activated by the driver if a secondary side error event has been detected to turn-off of the connected semiconductor slowly, which in turn shall prevent from excessive voltage overshoots to protect the semiconductor against destruction by over voltage. It is mandatory to populate a suitable soft-off gate resistor, otherwise the semiconductor will not be turned-off in case of a secondary side error. A detailed explanation of when the driver is activating the soft-off path is referred in chapter 4.8.

The gate resistor influences the IGBT switching time, switching losses, reverse bias safe operating area (RBSOA), short-circuit safe operating area (SCSOA), EMI, dV/dt, di/dt and reverse recovery current of the freewheeling diode. The gate resistor essentially optimizes the safe operation of the power semiconductor in accordance with the individual application parameters, e.g. IGBT technology, diode, switching frequency, losses, application layout, inductivity / stray inductance, DC-link voltage and driver capability. The complete design of an application must be viewed as a whole, with due considering of the above-mentioned parameters at least. Interacting and interfering effects within the whole application must be considered, evaluated and addressed. [4]

The minimum value of the gate resistors $R_{G(on)}$ and $R_{G(off)}$ could be calculated by the following equation:

$$R_{G(\mathrm{min})} = R_G + R_{G(int)} + R_E = \frac{V_{G(on)} - V_{G(off)}}{I_{out(peak)}}$$

The minimum allowed value of the $R_{G(softoff)}$ is 1Ω . Additional hints how to determine the values of the gate resistors are referred in [4].



Please note that some of SEMIKRON's driver cores using an ASIC internal N-channel MOSFET for Soft Off. To protect this MOSFET against stress when turning-off the TOP_ON/BOT_ON channel it is recommended to place the $R_{G(softoff)}$ resistor in series with the $R_{G(off)}$ resistor.

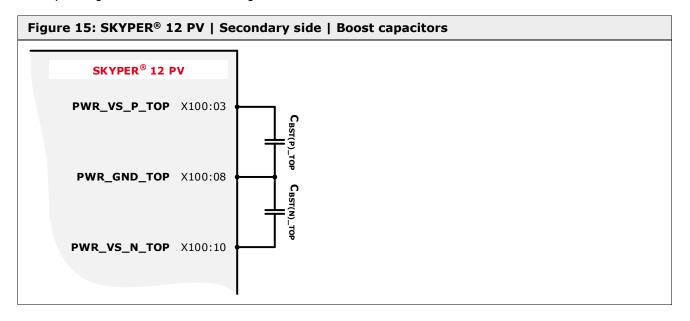
Since each turn-on and turn-off of a semiconductor means charging or discharging the input capacitance of the connected power semiconductor, the gate resistor has to be suitable for such pulse load. For this reason, SEMIKRON recommends the use of pulse current suitable resistors. The following table provides examples.



Description	Shape	Manufacturer	Art. no.
MELF resistors	MELF / MiniMELF SMD	Vishay Beyschlag, Vishay Draloric, Vitrohm	PRO MELF resistors, SMM0207, SMM 0204, ZCM series

4.11 External boost capacitors | Secondary side

The SKYPER® 12 PV allows driving of semiconductor power modules with a gate charge (Q_G) of up to $20\mu C$ per output. To stabilize the gate voltages $V_{G(on)}$ and $V_{G(off)}$ during the semiconductor switching, the use of boost capacitors for each output channel is recommended, if the connected gate charge is larger than 2.5 μC . For maximum effectiveness, these capacitors have to be placed as close as possible to the corresponding terminal as shown in Figure 15.



The required capacitance of the optional external boost capacitors can be estimated by the following equation:

$$C_{BST(P)}=C_{BST(N)}=A \times Q_G-4.7 \mu F$$
 for $2.5 \mu C < Q_G \leq 20 \mu C$
$$A=5 \dots 7 \frac{\mu F}{\mu C}$$
 IGBT 7 module
$$A=4 \frac{\mu F}{\mu C}$$
 IGBT module

Please note, when assembling boost capacitors at the secondary sides, also boost capacitors have to be assembled at the primary side, as shown in Figure 9.

$$C_{BST} = C_{BST(P)} = C_{BST(N)}$$





5. Protection features

5.1 Failure management

The SKYPER® 12 PV driver core detects several different error events on primary and secondary side. The driver's reaction on those events depends on the selected error mode, as described in chapter 4.8. The following table covers the possible error routine scenarios.

Table 7: SKYPE	Table 7: SKYPER® 12 PV Failure management					
	Conditions			Reaction		
Error event	Occurrence	CFG_ERR	nERR_OUT	Outputs	Turn-off path	
Undervoltage of power supply	primary side	HIGH/LOW	LOW immediately	OFF and locked, immediately, until reset	Standard	
nERR_IN at low-level	primary side	HIGH	LOW immediately	OFF, with next turn-off signal at the corresponding input Locked immediately	Standard	
				OFF & locked until reset		
		LOW	LOW immediately	OFF and locked, immediately, until reset	Standard	
Undervoltage of power supply	secondary side	HIGH	LOW immediately	OFF, affected channel immediately; 2 nd channel with next turn- off signal at the corresponding input Locked immediately OFF & locked until reset	Soft Off affected channel Standard not affected channel	
		LOW	LOW immediately	OFF and locked, immediately, until reset		
Short circuit detection (DSCP)	secondary side	HIGH	LOW immediately	OFF, affected channel immediately; 2 nd channel with next turn- off signal at the corresponding input Locked immediately	Soft Off affected channel Standard not affected channel	
				OFF & locked until reset		
		LOW	LOW immediately	OFF and locked, immediately, until reset		
nERR_IN at low-level	secondary side	HIGH	LOW immediately	OFF, affected channel immediately; 2nd channel with next turnoff signal at the corresponding input Locked immediately	Soft Off affected channel Standard not affected channel	
		1000	LOW	OFF and locked until reset		
		LOW	LOW immediately	OFF and locked, immediately, until reset		



If the driver has entered the error state, it must be reset before the driver resumes to operation mode. The driver could be reset under the following conditions:

- >30µs non-error condition (Reaction on customer side should happen within that time)
- $>9\mu s$ no input signals at TOP_IN/BOT_IN (Customer confirms error) After completing the reset sequence the driver returns 'ready for operation' by setting the $nERR_OUT$ output to high-level.

If the driver has entered error state because of an externally reported error event by the controller via the driver's primary side *nERR_IN* pin, the driver can be reset under the following conditions:

- > 30µs has elapsed until the external error event occurred
- > 9µs no input signals at TOP_IN/BOT_IN

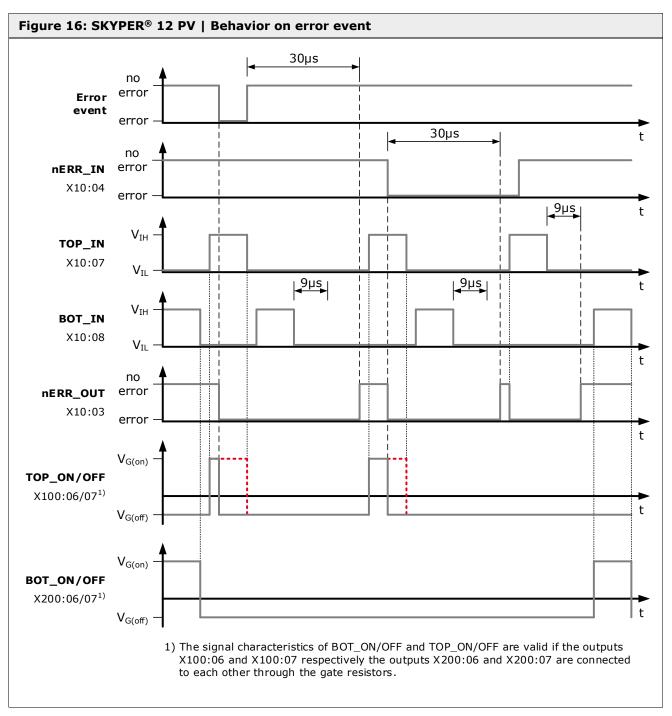
Important note

In this particular case the driver is ready for operation again, if the *nERR_OUT* output is set to high-level by the driver and the external error signal is removed. This behavior prevents deadlock situations, if several drivers are using the bi-directional HALT feature, as described in chapter 4.7.





The behavior of the driver on an error event is also shown in Figure 16. The red dotted lines show the behavior of the driver for the channel for which the error condition was not detected if the error configuration pin CFG_ERR is connected to PWR_VS.





5.2 Dead time and Interlock

The internal dead time generation of the SKYPER® 12 PV as well as the interlock feature can be selected via the configuration pin *CFG_IDT*. The following modes are available:

- Interlock enabled, 2µs dead time
- Interlock disabled, no dead time

Interlock enabled

To enable the interlock feature the *CFG_IDT* pin has to be connected to *PWR_GND*. The interlock feature is typically used when driving power semiconductor modules in half bridge configuration. The feature prevents the two outputs from being activated simultaneously, which would lead to a shorted DC-link connection (bridge shoot through). The interlock feature also allows controlling a power semiconductor module with one switching signal and its inverted signal at the driver's inputs *TOP_IN/BOT_IN*.

The internal timer which generates the dead time, starts with each turn-off command at the inputs TOP_IN/BOT_IN . As long as the dead time of 2µs has not elapsed, the driver locks the second output. If the pulse pattern generated by the customer's controller also includes a dead time, the resulting system dead time will be determined by either the controller or the driver, depending on whichever dead time duration is longer. The SKYPER® 12 PV does not add the internal generated dead time to the dead time of the pulse pattern of the controller.

Interlock disabled

If the interlock feature is disabled by connecting the configuration pin *CFG_IDT* to the *PWR_VS* pin, both outputs of the driver can be switched independently from each other. Hence, both output channels could be switched-on at the same time without blocking.

Table 8 shows the resulting system dead time depending on the configuration via the CFG IDT pin.

Table 8: SKYPER® 12 PV Resulting system dead time						
CFG_IDT	Interlock	Controller dead time	SKYPER dead time	Resulting dead time		
LOW	Enabled	No dead time	2µs	2µs		
LOW	Enabled	< 2µs	2µs	2µs		
LOW	Enabled	> 2µs	2µs	> 2µs		
HIGH	Disabled	2μs	No dead time	2µs		
HIGH	Disabled	No dead time	No dead time	No dead time		

Important Note

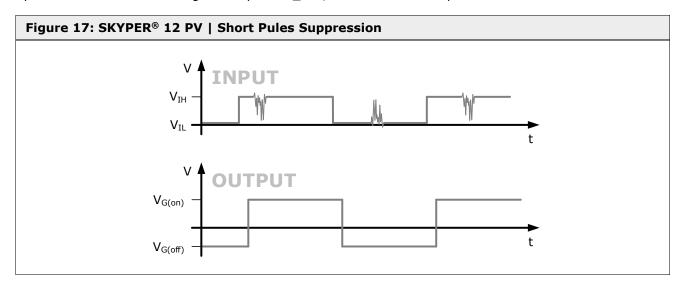
When the interlock function is disabled a bridge shoot through has to be prevented by the user's control unit.





5.3 Short pulse suppression (SPS)

The SKYPER® 12 PV driver suppresses short on- and off-pulses at the signal inputs *TOP_IN/BOT_IN* and, hence, enhances the interferences ruggedness. The time of suppression corresponds to the filter time set by the customer via the configuration pin *CFG_FLT*, as described in chapter 4.5.



5.4 Undervoltage lockout (UVLO)

The SKYPER® 12 PV driver permanently monitors the supply voltage of the primary side as well as both positive and both negative gate voltages of the secondary sides. If either the supply voltage or a positive gate voltage drops below the 'shutdown' threshold levels the driver enters into error state. The same applies when a negative gate voltage exceeds the 'shutdown' threshold level. Once entered into error state the driver executes its error routine as described in chapter 5.1.

The error condition resets when the supply voltage and both positive gate voltages have exceeded the 'non-error' threshold level and both negative gate voltages have dropped below the 'non-error' threshold level. The driver will be ready again for operation after reset, as described in chapter 5.1

Parameter	Min	Тур	Max
Primary side shutdown threshold	12.2V		
Primary side non-error threshold			13.9V
Secondary side shutdown threshold, positive gate voltage	9.4V		
Secondary side non-error threshold, positive gate voltage			13.3V
Secondary side shutdown threshold, negative gate voltage			-4.1V
Secondary side non-error threshold, negative gate voltage	-5.8V		



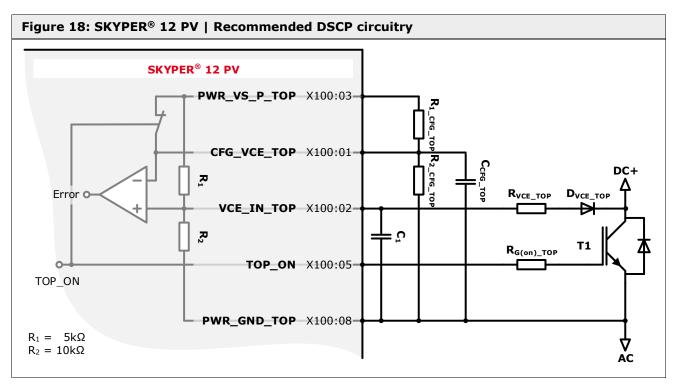
5.5 Dynamic short circuit protection by V_{CEsat}-monitoring (DSCP)

The dynamic short circuit protection feature monitors the Collector-Emitter voltage V_{CE} of the semiconductor during on-state. When the feature is enabled and the voltage at the VCE_IN input exceeds the voltage reference level at the CFG_VCE input the driver will enter into error state and will execute its error routine as described in chapter 5.1.

The DSCP feature can be disabled by connecting the CFG_VCE pin to the PWR_VS_P pin and the VCE_IN pin to the PWR_GND pin.

Important note

The DSCP feature is designed to detect short circuit conditions and forces the driver to react on the desaturation event of a semiconductor. It is explicitly stated that this function is designed to detect short circuit conditions and not to set a specific threshold to detect overcurrent situations e.g. of externally connected applications. SEMIKRON recommends to set the DSCP trip level to a value of 7V to 9V (voltage at the *CFG_VCE* pin) to prevent from unwanted accidently (false) triggered desaturation events due to a too small gap between the saturation voltage of the IGBT and the trigger level of the DSCP feature.





Recommended values				
Component	Value	Remark		
C ₁	≤1nF	Optional filter capacitors suppressing high-frequency interfering signals.		
C _{CFG}	-	Dimensioning according to chapter 5.5.2		
D _{VCE}	-	 The diode must block V_{CEmax}, when the IGBT switches off The diode must provide functional insulation Revers recovery charge of the diode causes additional pulse loads at R_{VCE} 		
R _{1_CFG}	~30kΩ	Dimensioning according to chapter 5.5.2		
R _{2_CFG}	-	Dimensioning according to chapter 5.5.2		
R _{G(on)}	-	Dimensioning according to chapter 4.10		
R _{VCE}	511Ω	Resistor should be surge proof		

5.5.1 DSCP | Functional description

As long as the driver keeps the connected semiconductor in off-state the high voltage diode D_{VCE} is operating in reverse direction. The voltage $V_{CE(IN)}$ at the VCE_IN pin is set to 10V by the voltage divider of R_1 and R_2 . The CFG_VCE pin is internally shorten to PWR_VS_P and pulls the voltage $V_{CE(ref)}$ at the CFG_VCE pin to PWR_VS_P . Hence, the output of the internal comparator is forced to its negative rail voltage.

When the driver initiates the turn-on process of the semiconductor the internal bypass will be interrupted and the capacitor C_{CFG} discharges until the voltage level, defined by the voltage divider of R_{1_CFG} and R_{2_CFG} , is reached. The trip level during the on-state of the semiconductor has reached its static level $(V_{CE(ref)} = V_{CE(stat)})$.

Simultaneously to the discharging process of the capacitor C_{CFG} the semiconductor starts conducting and reducing the collector-emitter voltage V_{CE} to V_{CEsat} . When the Collector-Emitter voltage of the IGBT falls below 10V the high-voltage diode D_{VCE} is starting to operate in forward direction. Now, the voltage $V_{CE(IN)}$ at the VCE_IN pin follows the collector-emitter voltage of the semiconductor with an offset caused by the forward current I_F of the high-voltage diode D_{VCE} multiplied by the resistance of R_{VCE} plus the voltage drop V_F of the high-voltage diode.

The DSCP feature is active from the moment the voltage $V_{\text{CE(ref)}}$ at the *CFG_VCE* pin is below 10V. The time elapsed from initiating the turn-on process of the semiconductor until the DSCP feature is activated is called blanking time $t_{\text{bl(VCE)}}$.

In active state the DSCP triggers an error event, if the voltage $V_{CE(IN)}$ at the VCE_IN pin exceeds the voltage $V_{CE(ref)}$ of the CFG_VCE pin.

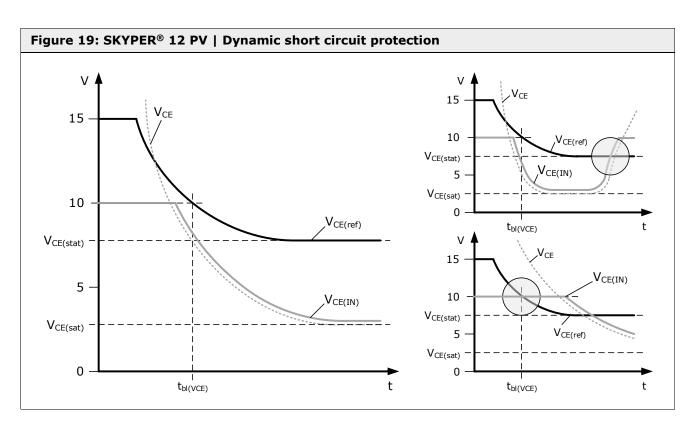
Figure 19 shows on the left side the above described process for a well-configured blanking time $t_{bl(VCE)}$ and static threshold voltage $V_{CE(stat)}$.

The upper right side of Figure 19 shows a desaturation event of an IGBT during the DSCP feature is active. In the moment when the voltage $V_{\text{CE}(IN)}$ exceeds the threshold voltage $V_{\text{CE}(ref)}$ the driver enters into error state.

The lower right side shows an error condition, caused by a too short determined blanking time $t_{bl(VCE)}$. The threshold voltage $V_{CE(ref)}$ has already fallen below 10V before the monitored voltage $V_{CE(IN)}$ is below that level.







5.5.2 DSCP | Calculation hints

The following equations help to select all relevant parameters of the DSCP feature:

Equation (1) Calculation of the static trip level $(V_{CE(ref)} = V_{CE(stat)})$

$$V_{CE(stat)} = PWR_VS_P \cdot \frac{R_{2_CFG}}{R_{1_CFG} + R_{2_CFG}}$$

Equation (2) Calculation of R_{2_CFG} for a certain value of $V_{CE(stat)}$

$$R_{2_CFG} = \frac{R_{1_CFG} \cdot V_{CE(stat)}}{PWR_VS_P - V_{CE(stat)}}$$

Equation (3) Calculation of the blanking time $t_{bl(VCE)}$ depending on the values of C_{CFG} ; R_{1_CFG} ; R_{2_CFG} ; $V_{CE(stat)}$

$$t_{bl(VCE)} = -C_{CFG} \cdot \frac{R_{1_CFG} \cdot R_{2_CFG}}{R_{1_CFG} + R_{2_CFG}} \cdot \ln \left(\frac{\frac{10V}{PWR_VS_P} \cdot \left(R_{1_CFG} + R_{2_CFG} \right) - R_{2_CFG}}{R_{1_CFG}} \right)$$

Equation (4) Calculation of the voltage $V_{CE(IN)}$ at the VCE_IN input depending on the values of V_{CE} ; R_{VCE} ; $V_{D\ VCE}$

$$V_{CE(IN)} = \frac{R_1 \cdot R_2}{R_1 \cdot R_2 + (R_1 + R_2) \cdot R_{VCE}} \cdot V_{CE} + \frac{\left(V_{D_VCE} + \frac{PWR_VS_P \cdot R_{VCE}}{R_1}\right) \cdot R_1 \cdot R_2}{R_1 \cdot R_2 + (R_1 + R_2) \cdot R_{VCE}}$$

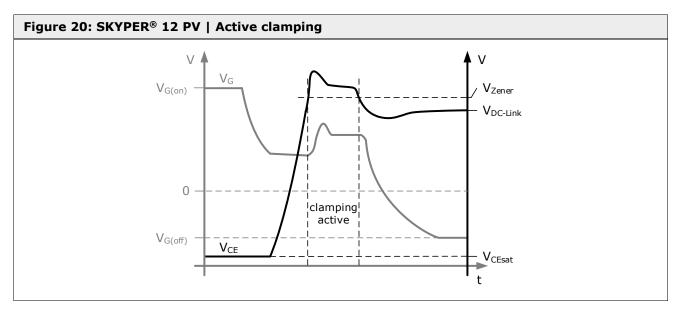


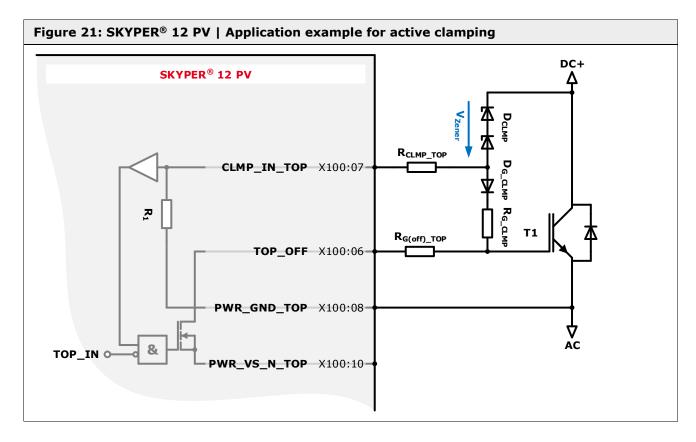


5.6 Active clamping

The driver offers the possibility to reduce over voltages during the semiconductor's turn-off process by using an active clamping feature. Figure 21 shows an example of an active clamping circuitry based on Zener diodes. The total breakdown voltage of the Zener diodes D_{CLMP} determine the voltage level when the clamping starts. If, during a turn-off of the IGBT the collector-gate voltage V_{CG} raises beyond the break down voltage V_{Zener} the clamping diodes will get conductive. This leads to a current feeding energy into the gate of the IGBT and gradually switches the IGBT on again, until the V_{CG} voltage is reduced below the V_{Zener} reference.

The $CLMP_IN$ input indicates the driver that the collector-gate voltage raised above V_{zener} , if the voltage at the input exceeds the threshold of 13V. When entering active clamping mode the driver sets the output channels to high impedance, which reduces the losses on the driver.







Important Note

During the clamping process the IGBT is working in a typically not specified linear mode. The suitability of the power semiconductor to operate under such linear conditions, the danger of creating oscillations implying additional considerable loss must be considered and verified. In any case active clamping must not be operated during standard switching to avoid thermal overstress and reduced IGBT lifetime.

Parameter	Min	Тур	Max
Threshold high CLMP-input	-	-	13 V
Threshold low CLMP-input	2 V	-	-

5.7 Soft Off

The SKYPER® 12 PV provides a separate turn-off path *TOP_SOFTOFF/BOT_SOFTOFF* activated by the driver, if an error event is detected on the secondary side, as described in chapter 5.1. Switching-off a semiconductor via the soft-off path aims to reduce the switching speed of the semiconductor and, hence, the over voltage caused by the di/dt through the system's stray inductances is decreased.

Recommendation

Usually the Soft Off resistor is roughly 10 times as high as the standard $R_{G(off)}$. However, the proper value has to be very carefully evaluated in the system in accordance with the individual application parameters. The setup is a balance between staying within the maximum permitted short circuit time of the IGBT and on the other hand reducing the overvoltage below the maximum collector-emitter voltage of the IGBT. Please observe the individual SCSOA of your power semiconductor.



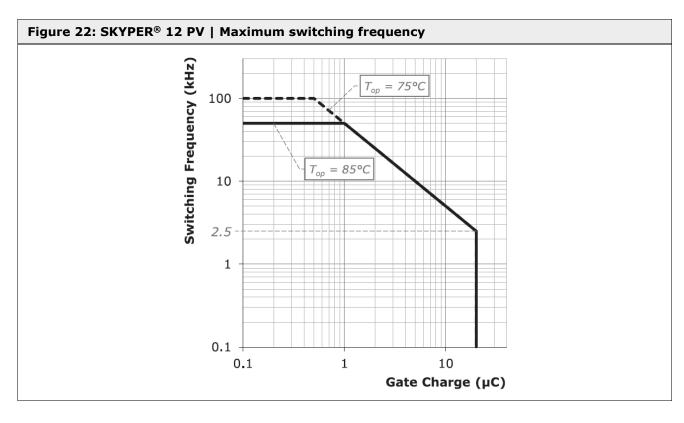


5.8 Safe short circuit turn-off in multilevel topology

Power semiconductors in multilevel NPC applications need a careful control, especially in error conditions like a short circuit. A dedicated 3-L topology turn-off sequence avoids damaging the semiconductors due to an unappropriated turn-off sequence. The integrated DSCP, Soft Off and active clamping features ensure that the SKYPER® 12 PV allows proper control of the power semiconductors in multilevel applications. And thanks to the advanced error management provisions realized in the ASIC chipset the SKYPER® 12 PV safely handles even short circuit conditions.

Detailed information how to use the SKYPER® 12 PV driver core in multilevel applications are referred in the Application Note AN19-001 "Gate Driver Configuration and Short Circuit Protection for 3-Level Topologies". Thoroughly reading this document is highly recommended before starting tests of multilevel topologies.

6. Electrical characteristic





7. Product Qualification

Table	Table 9: SKYPER® 12 PV Routine tests					
test	test category	test description	Standard			
AOI	Automated Opt. Inspection	Control of accurate placement of components/ of solder joints, 100%	SEMIKRON			
ICT	In-Circuit Test	Test of the populated PCB, checking the correctly fabrication, 100%	SEMIKRON			
FAT	Function Test	Supply current, gate on/off, UVP, error, 100%	SEMIKRON			

Table 10: SKYPER® 12 PV Approval tests					
test	test category	test description ¹	Standard		
EP	Electrical Parameters	9amb = -40°C / +85°C	SEMIKRON		
ST	STEP Test	20x 10µs to 2s interruption	IEC 61000-4-29		
ISO	Isolation	5.0 kV AC rms, 60s	IEC 62109		
TC	Thermal Cycling	500 cycles a 1h, -40°C – 85°C	IEC 60068-2-14		
TH	Temperature Humidity	85°C, 85% RH, 1000h, passive and at high voltage	IEC 60068-2-67		
BST	Burst	Power terminals: 4kV; Control terminals: 2kV	IEC 61000-4-4		
CC	Climate Change	-15°C to 85°C; 10% to 85%; 10 cycles a 8h	IEC 60068-2-30		
ESD	ESD	Contact discharge: 6kV; Air discharge: 8kV	IEC 61000-4-2		
RFF	Radio Frequency	80 MHz - 1GHz, 20 V/m, 80% AM 1kHz	IEC 61000-4-3		
RFD	RF Conducted Disturbance	150 kHz - 80 MHz, 20 V/m, v+h, 80 % AM 1kHz	IEC 61000-4-6		
VB	Vibration	Sinusoidal 20Hz 500Hz, 5g 26 Sweeps per axis (x, y, z) Random 10Hz 2000Hz 3g 2 h per axis (x, y, z)	IEC 60068-2-6		
SH	Shock	Half-sinus pulse, 30g, 6000 shocks, 11ms, $\pm x$, $\pm y$, $\pm z$	IEC 60068-2-27		

 $^{^{1}}$ The test conditions are not the maximum applicable conditions for the products. The characteristics of the products are indicated in the data sheet





8. Environmental conditions

Table 11: SKYPER® 12 PV Environm		Norm / Standard
Insulation parameters	Rating	-
Grid voltage	690V	IEC 61800-5-1
Pollution Degree	PD II	IEC 61800-5-1
Maximum altitude	2000 meter above sea	IEC 61800-5-1
Overvoltage category	OVC III	IEC 61800-5-1
Isolation resistance test, primary to secondary side (2 pieces per lot as series test, power and signal transformers are 100% tested as series test)	5000 V AC rms, 60s	IEC 61800-5-1
Rated insulation voltage	8 kV Cat. III	IEC 60664-1
Partial discharge	2.2kV/1.8kV	IEC 61800-5-1
Creepage distance primary to secondary side	20.9mm	IEC 61800-5-1
Clearance distance primary to secondary side	14.0mm	IEC 61800-5-1
Creepage distance secondary to secondary sides	10.5mm	IEC 61800-5-1
Clearance distance secondary to secondary	6.1mm	IEC 61800-5-1
CTI rating of the PCB	II (400-600)	IEC 61800-5-1
CTI of the transformers	I (600)	IEC 61800-5-1
Climate	Rating	Norm / Standard
Climate class	3K3	IEC 60721-3-3
Environmental conditions	Rating	Norm / Standard
Operating/storage temperature	-40 +85 °C	
High humidity	85 °C, 85%	
Flammability	Heavy flammable materials only	UL94 V0
		RoHS / WEEE / China RoHS



EMC Condition	Rating	Norm / Standard
ESD	6 kV contact discharge / 8 kV air discharge	IEC 61000-4-2 IEC 61800-3
Burst	≥ 2kV on adaptor board for signals ≥ 4kV for AC lines	IEC 61000-4-4 IEC 61800-3
Immunity against external interference	≥ 30V/m 80MHz - 1000 MHz	IEC 61000-4-3 IEC 61800-3
Immunity against conducted interference	≥ 20V 150kHz – 80MHz	IEC 61000-4-6 IEC 61800-3
Shock Vibration	Rating	Norm / Standard
Vibration	Sinusoida l 20Hz 500Hz, 5g, 26 sweeps per axis (x, y, z) Random 10Hz 2000Hz, 3g, 2 h per axis (x, y, z)	IEC 60068-2-6
Shock	6000 Shocks (6 axis; +-x, +-y, +-z, 1000 shocks per axis), 30g, 18ms (The connection between driver and PCB was reinforced by a support post during the test.)	IEC 60068-2-27



9. Marking

Figure 23: SKYPER® 12 PV | Label

Every driver core is marked with a data matrix label. The marking contains the following items.

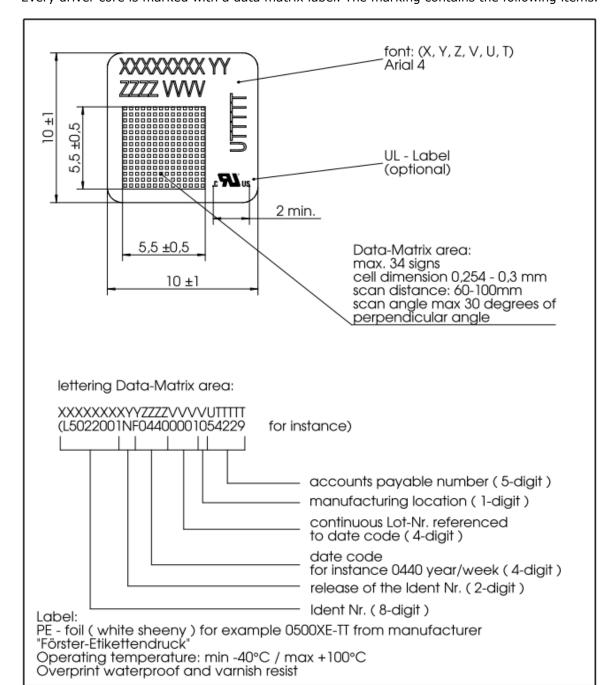




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IMPORTANT INFORMATION AND WARNINGS

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